



ELECTRONICS, INC.  
44 FARRAND STREET  
BLOOMFIELD, NJ 07003  
(973) 748-5089  
<http://www.nteinc.com>

**NTE3133, NTE3135,  
NTE3136, NTE3138, NTE3139  
Light Emitting Diode – 1.8mm  
Surface Mount Type**

**Features:**

- All Plastic Mold Type w/Water Clear Lens:  
    NTE3133 (Super Yellow-Green, AlGaP/GaAs)  
    NTE3135 (Orange, AlInGaP/GaAs)  
    NTE3136 (Super Orange, AlInGaP/GaAs)  
    NTE3138 (Super Red)  
    NTE3139 (Super Blue, GaAlAs/GaAlAs)

**Absolute Maximum Ratings:** ( $T_A = +25^\circ\text{C}$  unless otherwise specified)

Power Dissipation, $P_D$		
All Devices .....	.....	100mW
NTE3139 Only .....	.....	120mW
Forward Current, $I_F$		
Continuous		
All Devices .....	.....	25mA
NTE3138 Only .....	.....	20mA
Peak (Note 1)		
All Devices .....	.....	50mA
NTE3138 (Note 2), NTE3139 Only .....	.....	100mA
Reverse Voltage, $V_R$		
All Devices .....	.....	5V
NTE3139 Only .....	.....	4V
LED Junction Temperature, $T_J$	.....	+100°C
Operating Temperature Range, $T_{opr}$		
All Other Devices .....	.....	-30° to +85°C
NTE3138 Only .....	.....	-20° to +80°C
NTE3139 Only .....	.....	-25° to +85°C
Storage Temperature Range, $T_{stg}$		
All Devices .....	.....	-40° to +100°C
NTE3138 Only .....	.....	-30° to +100°C
Lead Temperature (During Soldering, 0.62 (1.6mm) from case), $T_L$		
All Devices (3sec max) .....	.....	+240°C
NTE3138 Only (5sec max) .....	.....	+260°C

Note 1.  $t_p = 1\mu\text{sec}$  pulse, 0.3% duty cycle

Note 2.  $t_p \leq 100\mu\text{sec}$  pulse,  $\leq 1\%$  duty cycle

**Electrical Characteristics:** ( $T_A = +25^\circ\text{C}$  unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
View Angle of Half Power All Devices	2θ/2	$I_F = 20\text{mA}$	–	24	–	Degree
NTE3138			–	25	–	Degree
Forward Voltage NTE3133	$V_F$	$I_F = 20\text{mA}$	–	2.20	2.40	V
NTE3135, NTE3136			–	2.00	2.60	V
NTE3138			2.0	–	2.2	V
NTE3139			–	3.5	4.0	V
Reverse Current NTE3139 Only	$I_R$	$V_R = 5\text{V}$	–	–	10	uA
–			–	–	60	uA
Luminous Intensity NTE3133	$I_V$	$I_F = 20\text{mA}$ (Note 3)	450	900	–	mcd
NTE3135, NTE3136			900	1300	–	mcd
NTE3138			800	1200	–	mcd
NTE3139			750	1500	–	mcd
Peak Emission Wavelength NTE3133	$\lambda_p$	$I_F = 20\text{mA}$	–	575	–	nm
NTE3135, NTE3136			–	620	–	nm
NTE3138			655	660	665	nm
NTE3139			–	468	–	nm
Dominant Wavelength NTE3133	$\lambda_d(\text{HUE})$	$I_F = 20\text{mA}$ (Note 4)	–	572	–	nm
NTE3135, NTE3136			–	615	–	nm
NTE3139			470	472	475	nm
Spectrum Width of Half Valve NTE3139 Only	$\Delta\lambda$	$I_F = 20\text{mA}$	–	20	–	nm
–			–	30	–	nm
Terminal Capacitance NTE3133	$C_t$	$V = 0\text{V}, F = 1\text{MHz}$	–	35	–	pF
NTE3135, NTE3136			–	15	–	pF
Optic Rise Time (NTE3139 Only)	$\tau$	$I_F = 20\text{mA}$	–	30	–	ns

Note 3. Tolerance: 30%, measured using Exeltron 2001.

Note 4. The dominate wavelength,  $\lambda_d$ , is derived from the CIE Chromaticity Diagram and represents the color of the device.

